


First Named Inventor	Zhongze Wang	<b>REPLY UNDER 37 C.F.R. §1.116 - EXPEDITED PROCEDURE - TECHNOLOGY CENTER 2800</b>  
Serial No.	10/758,059	
Filing Date	January 15, 2004	
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Confirmation No.	5110	
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<b>Title: FET HAVING EPITAXIAL SILICON GROWTH</b>		

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In response to the Final Office Action mailed April 4, 2006, please consider the  
 following:

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*06/22/2006*